300 mA / 13 V Adjustable CMOS LDO Regulator

Description

The CAT6201/CAV6201B is a 13 V rated 300 mA CMOS low dropout regulator that provides fast response time to load current and line voltage changes in an automotive environment.

CAT6201/CAV6201B features a low R_{ON} P-channel pass element with internal control circuitry which prevents reverse current flow should the voltage at V_{OUT} exceed V_{IN} as in the case of the car's battery voltage accidentally being applied to V_{OUT} .

Thermal protection and current limiting circuitry combine to protect the pass device against faults and abuse. Current limiting is user controlled through a single resistor to ground. A fault output (FLT) provides an alert should an over–current event or thermal shutdown occur.

CAT6201/CAV6201B comes on-line gracefully even though it may be driving heavy capacitive loads thanks to built-in soft-start circuitry. Its output is protected against accidental connection to voltages greater than V_{IN} and will not conduct current backwards into its supply.

CAT6201/CAV6201B is available in 8-pad 2 mm x 3 mm TDFN package.

Features

- Guaranteed 300 mA Continuous Output Current
- Low Dropout Voltage of 250 mV Typical at 300 mA
- Input Voltage Range: 3.3 V to 13.5 V
- User Adjustable Output Voltage
- User Programmable Current Limit
- Fault Output to Indicate Under-voltage, Current Limiting or Thermal Shutdown has Occurred
- Fault Blanking: 3 ms
- V_{OUT} Withstands Battery Fault Voltages of up to 14 V
- Soft-Start Prevents Current Surges
- Stable with Ceramic Output Capacitor
- ±1.5% Output Voltage Initial Accuracy
- ±2.5% Accuracy Over Temperature
- Thermal Protection
- 8 Pad TDFN Package
- CAV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



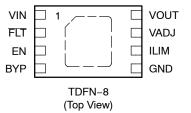
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TDFN-8 VP2 SUFFIX CASE 511AK

PIN CONNECTIONS



MARKING DIAGRAMS



HKB = CAT6201VP2-GT3 or CAV6201BVP2-GT3

L = Assembly Location

AA = Last Two Digits of Assembly Lot Number

Y = Production Year (Last Digit)

M = Production Month (1–9, O, N, D)

= Pb-Free Microdot

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

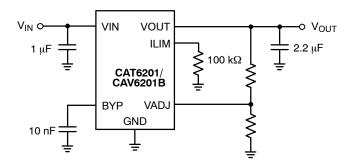


Figure 1. CAT6201/CAV6201B Typical Application

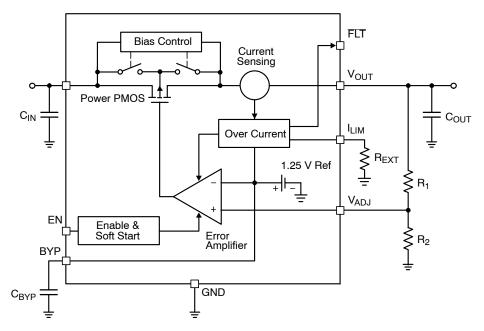


Figure 2. CAT6201/CAV6201B Functional Block Diagram

Table 1. PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Description		
1	VIN	Supply voltage input		
2	FLT	Fault indicator (active low)		
3	EN	Enable input (active high)		
4	BYP	A capacitor between BYP and GND controls the regulator's turn-on speed and improves PSRR		
5	GND	Ground reference		
6	ILIM	Current limit control pin		
7	VADJ	Output voltage adjustment		
8	VOUT	LDO Output Voltage		
Pad	-	Backside pad in center of package provides thermal contact for cooling, typically via the PCB ground plane. This pad is electrically active and connected to GND internally. An external Ground connection is not required and the pad may be left floating.		

Table 2. ABSOLUTE MAXIMUM RATINGS

Rating	Value	Unit
V _{IN} , V _{OUT} , EN	0 to 16	V
All other pins	-0.3 to +6.0	V
Junction Temperature, T _J	+150	°C
Power Dissipation, P _D	Internally Limited (Note 1)	mW
Storage Temperature Range, T _S	-65 to +150	°C
Lead Temperature (soldering, 5 sec.)	260	°C
ESD Rating (Human Body Model)	1000	V
ESD Rating (Machine Model)	200	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 3. RECOMMENDED OPERATING CONDITIONS (Note 2)

Parameter	Range	Unit
V _{IN} , V _{OUT} , EN	3.3 to 13.5	V
All other pins	0 to 6.0	V
Junction Temperature Range, T _J	-40 to +125	°C
Package Thermal Resistance (SOIC), θ_{JA}	235	°C/W
Package Thermal Resistance (TDFN), θ_{JA}	92	°C/W

^{2.} The device is not guaranteed to work outside its operating rating.

^{1.} The maximum allowable power dissipation at any T_A (ambient temperature) is $P_{Dmax} = (T_{Jmax} - T_A)/\theta_{JA}$. Exceeding the maximum allowable power dissipation will result in excessive die temperature, and the regulator will go into thermal shutdown.

Pin Function

VIN is the supply pin for both the LDO's operation and the load the LDO is driving. It is recommended that a 1 μ F ceramic bypass capacitor be placed between the V_{IN} pin and ground in close proximity to the device. When using longer connections to the power supply, C_{IN} value can be increased without limit. The operating input voltage range is from 3.3 V to 13.5 V.

FLT is an active low open–drain output indicating one of 3 fault conditions:

- 1. Input under-voltage: input is below the intended output voltage
- 2. Over-current. Brief over-current events are masked by a 3 ms time delay. CAT6201/CAV6201B will limit current anytime the load tries to draw more than the maximum allowed, however reporting of this event will occur only if the event lasts longer than the delay timer. Events terminating before the timer reaches its full count are ignored and the timer is reset.
- 3. Over-temperature shutdown has occurred.

EN is an active HIGH logic level input for switching the regulator's output between ON and OFF. A weak internal pull down assures that if EN pin is left open, the circuit is disabled.

BYP controls the soft–start feature for the regulator. When large capacitive loads are present at the regulator's output, enabling the regulator will produce large current surges on the $V_{\rm IN}$ supply line. To reduce these surges the regulator can be turned on gently by connecting a capacitor between the BYP pin and ground. The larger the capacitance value the more slowly $V_{\rm OUT}$ approaches its programmed value. The table below gives a list of common capacitor values and their resulting turn–on times. If the soft–start feature is not desired, this pin should be left floating.

Capacitance [nF]	t _{ON} [ms]
0	0.2
10	1
100	10

GND is the ground reference for the LDO in the TDFN package, center metal pad is internally connected to GND. If electrical contact is made with this pad, it should be to GND and/or the ground plane of the PCB. Connection to the ground plane enhances thermal conductivity drawing heat out of the package and into the surrounding PCB.

ILIM stands for Current Limit and is the control input for setting the point at which the current limit is invoked. I_{LIM} is defined as the current at which V_{OUT} is still within 80% of its nominal value and should not be confused with I_{SC} , the

short circuit current, measured at $V_{OUT} = 0$ V, which is typically 100 mA greater than I_{LIM} .

A resistor R_{EXT} placed between I_{LIM} and GND selects the trip current according to a formula:

$$I_{LIM} = I_{LIM0} + \frac{Current_Limit_Factor(CLF)}{R_{EXT}}$$
 (eq. 1)

 I_{LIM0} is the built-in minimum current limit (typically 150 mA), and CLF is a numerical value (typical 30,000 Volts) which relates the allowable load current to a resistance value. The value of this resistor is determined by the following equation:

$$R_{EXT}(\Omega) = \frac{CLF(V)}{I_{LIM}(A) - I_{LIM0}(A)}$$
 (eq. 2)

It is recommended that I_{LIM} be set to at least 50% higher than the maximum intended continuous I_{OUT} .

Example: Set I_{LIMIT} = 600 mA

$$R_{EXT}(\Omega) = \frac{30,000 \text{ V}}{0.6 \text{ A} - 0.15 \text{ A}} = 68 \text{ K}\Omega$$
 (eq. 3)

VADJ is the output voltage control pin. A resistor divider placed between VOUT and GND whose center point connects to VADJ sets the LDO regulator's output voltage. Typical VADJ value is 1.25 V. The current through the resistor divider can be anywhere between 10 µA and 1 mA. The higher this current is, the lower the noise.

For best performance R1 and R2 should have similar temperature coefficients, otherwise output voltage accuracy will be compromised.

$$V_{OUT} = V_{ADJ} \left(1 + \frac{R_1}{R_2} \right)$$
 (eq. 4)

VOUT is the LDO regulator output. A small $2.2 \mu F$ ceramic bypass capacitor is required between VOUT and ground. For better transient response, its value can be increased to $4.7 \mu F$. This capacitor should be located near the device.

VOUT is protected against short circuits and over-temp operation by internal circuitry. In the event of an over-current, the LDO behaves like a current source, limiting current at the output. The maximum current allowed is set by R_{EXT}, the resistor between I_{LIM} and GND. If the load attempts to draw more than the allowed current, VOUT and IOUT decrease together and thus limit the total power delivered.

VOUT is protected against the application of voltages greater than VIN. For example, in automotive applications, if CAT6201/CAV6201B is powering a remote load and damage occurs to a wiring harness shorting a powered line, Battery + for instance, to VOUT, CAT6201/CAV6201B will not be damaged by this higher voltage being applied to VOUT.

Table 4. ELECTRICAL CHARACTERISTICS

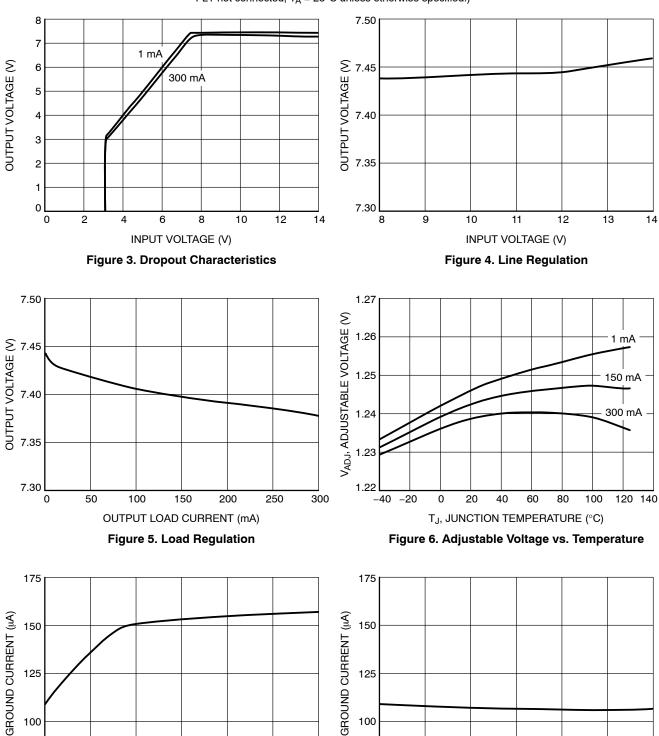
 $(V_{IN}=V_{OUT}+1~V,~V_{EN}=High,~I_{OUT}=1~mA,~C_{IN}=1~\mu F,~C_{OUT}=2.2~\mu F,~R_{EXT}=68~k\Omega,~ambient~temperature~of~25^{\circ}C~(over~recommended~operating~conditions~unless~specified~otherwise).$ **Bold numbers** apply for the entire junction temperature range.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{IN}	Input Voltage		3.3		13.5	V
V _{OUT}	Output Voltage		V _{ADJ}		12.5	
V _{ADJ}	ADJ Voltage		1.232	1.250	1.268	V
I _{ADJ}	ADJ Input Current			0.5	2.0	μΑ
TC _{OUT}	Output Voltage Temp. Coefficient	I _{OUT} = 10 mA		100		ppm/°C
V_{R-LINE}	Line Regulation	V _{OUT} + 1 V < V _{IN} < 13.5 V	-0.2	±0.1	+0.2	%/V
			-0.4		+0.4	
V_{R-LOAD}	Load Regulation	I _{OUT} = 1 mA to 300 mA		0.7	2	%
V_{DROP}	Dropout Voltage (Note 3)	I _{OUT} = 300 mA		250	350	mV
I _{GND}	Ground Current	I _{OUT} = 0 mA		100	150	μΑ
		I _{OUT} = 300 mA		160	300	
I _{GND-SD}	Shutdown Ground Current	V _{EN} < 0.4 V		0.5	2	μΑ
PSRR	Power Supply	f = 1 kHz, C _{BYP} = 10 nF		62		dB
	Rejection Ratio	f = 20 kHz, C _{BYP} = 10 nF		52		
T _{ON}	Turn-On Time	C _{BYP} = 10 nF V _{OUT} = 0% – 100%		700		μs
I _{sc}	Output short circuit current	V _{OUT} < 0.8 V R _{EXT} = 68 K	500	650	800	mA
		V _{OUT} < 0.8 V I _{LIM} = OPEN		200		
I _{LIM}	Output current limit	V _{OUT} = 80% of V _{OUT} measured at a load of 1 mA R _{EXT} = 68 K	400	450	600	mA
		V _{OUT} = 80% of V _{OUT} measured at a load of 1 mA I _{LIM} = OPEN	120	150	180	
CLF	Current Limit Factor	V _{OUT} < 0.8 V	24	30	36	KV
t _{FD}	Fault Delay		1.5	3	6	ms
V _{IN-UVLO}	Under voltage lockout threshold		2.85	3.1	3.25	V
ESR	R _{OUT} equivalent series resistance		5		500	mΩ
ENABLE IN	IPUT	·				
V_{HI}	Logic High Level	V _{IN} = 3.3 to 13.5 V	2			V
V_{LO}	Logic Low Level	V _{IN} = 3.3 to 13.5 V			0.4	V
I _{EN}	Enable Input Current	V _{EN} = 0.4 V		0.15	1	μΑ
		$V_{EN} = V_{IN}$		3	5	
THERMAL	PROTECTION	<u> </u>				
T_{SD}	Thermal Shutdown			140		°C
T _{HYS}	Thermal Hysteresis		·	10		°C

^{3.} Dropout voltage is defined as the input-to-output differential at which the output voltage drops 2% below its nominal value. During test, the input voltage stays always above the minimum 3.3 V. The given values are for V_{OUT} = 7.5 V.

TYPICAL CHARACTERISTICS (shown for 7.5 V output)

 $(V_{IN}=8.5~V,~R_1=5.1~k\Omega,~R_2=1~k\Omega,~C_{IN}=1~\mu\text{F},~C_{OUT}=2.2~\mu\text{F},~C_{BYP}=10~n\text{F},~R_{EXT}=68~k\Omega,} \\ \overline{FLT}~not~connected,~T_A=25^{\circ}C~unless~otherwise~specified.)$



OUTPUT LOAD CURRENT (mA)

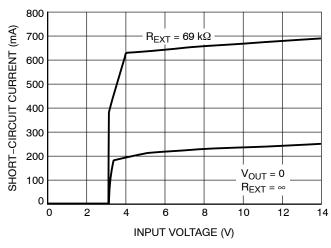
Figure 7. Ground Current vs. Load Current

TEMPERATURE (°C) Figure 8. Ground Current vs. Temperature

-25

TYPICAL CHARACTERISTICS (shown for 7.5 V output)

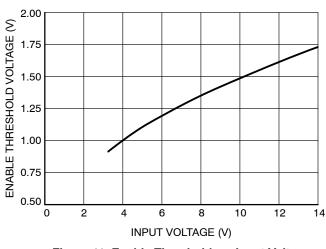
 $(V_{IN}=8.5~V,~R_1=5.1~k\Omega,~R_2=1~k\Omega,~C_{IN}=1~\mu\text{F},~C_{OUT}=2.2~\mu\text{F},~C_{BYP}=10~n\text{F},~R_{EXT}=68~k\Omega,} \\ \overline{FLT}~not~connected,~T_A=25^{\circ}C~unless~otherwise~specified.)$



200 175 GROUND CURRENT (µA) 150 125 100 75 50 25 0 8 10 6 12 0 14 INPUT VOLTAGE (V)

Figure 9. Output Short-circuit Current vs. Input Voltage

Figure 10. Ground Current vs. Input Voltage



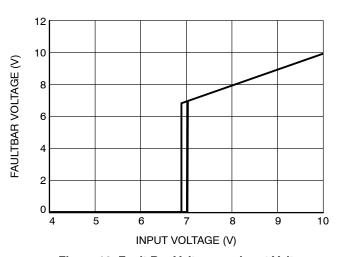
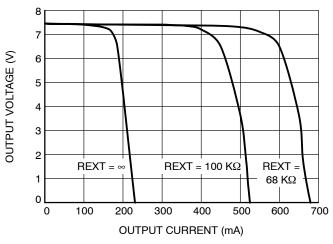


Figure 11. Enable Threshold vs. Input Voltage

Figure 12. Fault Bar Voltage vs. Input Voltage



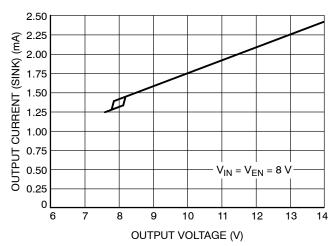


Figure 13. Output Voltage vs. Load Current

Figure 14. Output Current (Sink) vs. Output Voltage

TYPICAL CHARACTERISTICS (shown for 7.5 V output)

 $(V_{IN}=8.5~V,~R_1=5.1~k\Omega,~R_2=1~k\Omega,~C_{IN}=1~\mu F,~C_{OUT}=2.2~\mu F,~C_{BYP}=10~nF,~R_{EXT}=68~k\Omega,$ T_A = 25°C unless otherwise specified. All transient characteristics are generated using the evaluation board CAT6201EVAL1.)

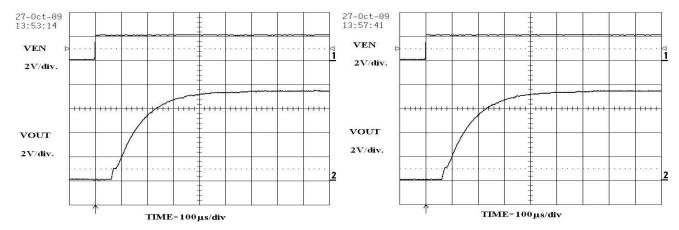


Figure 15. Enable Turn-On (No Load)

Figure 16. Enable Turn-On (22 Ω Load)

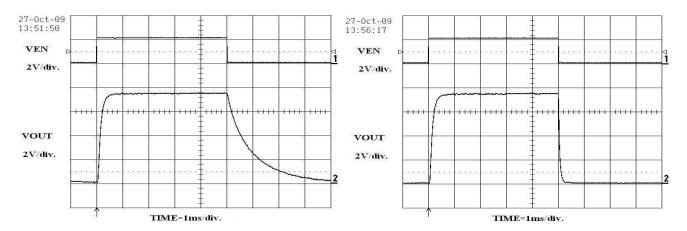


Figure 17. Enable Operation (No Load)

Figure 18. Enable Operation (22 Ω Load)

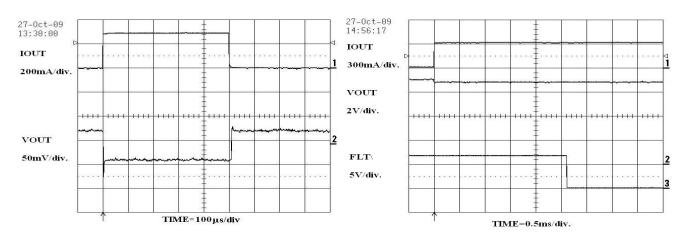
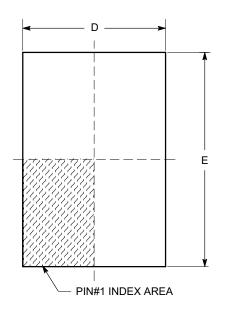


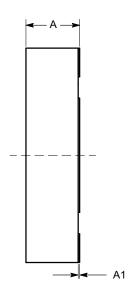
Figure 19. Load Transient Response (1 mA to 330 mA)

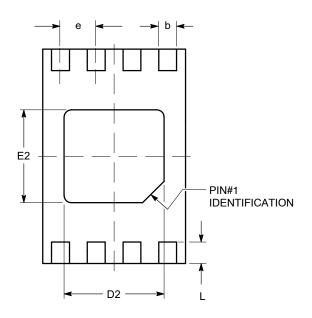
Figure 20. Fault Operation (VIN = 7 V and 22 Ω Load)

PACKAGE DIMENSIONS

TDFN8, 2x3 CASE 511AK-01 ISSUE A





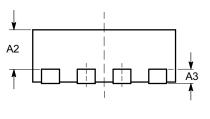


TOP VIEW

SIDE VIEW

BOTTOM VIEW

SYMBOL	MIN	NOM	MAX
Α	0.70	0.75	0.80
A1	0.00	0.02	0.05
A2	0.45	0.55	0.65
A3	0.20 REF		
b	0.20	0.25	0.30
D	1.90	2.00	2.10
D2	1.30	1.40	1.50
E	2.90	3.00	3.10
E2	1.20 1.30		1.40
е	0.50 TYP		
L	0.20 0.30 0.40		



FRONT VIEW

Notes:

- (1) All dimensions are in millimeters.(2) Complies with JEDEC MO-229.

ORDERING INFORMATION

Device Order Number	Specific Device Marking	Package Type	Lead Finish	Shipping (Note 5)
CAT6201VP2-GT3	НКВ	TDFN-8	NiPdAu	3,000 / Tape & Reel
CAV6201BVP2-GT3	НКВ	TDFN-8	NiPdAu	3,000 / Tape & Reel

- 4. For additional package and temperature options, please contact your nearest ON Semiconductor Sales office.
- For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
- 6. For detailed information and a breakdown of device nomenclature and numbering systems, please see the ON Semiconductor Device Nomenclature document, TND310/D, available at www.onsemi.com.

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